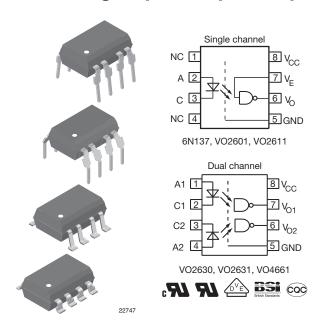


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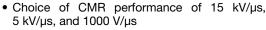
High Speed Optocoupler, Single and Dual, 10 MBd



DESCRIPTION

The 6N137, VO2601, and VO2611 are single channel 10 MBd optocouplers utilizing a high efficient input LED coupled with an integrated optical photodiode IC detector. The detector has an open drain NMOS-transistor output, providing less leakage compared to an open collector Schottky clamped transistor output. The VO2630, VO2631, and VO4661 are dual channel 10 MBd optocouplers. For the single channel type, an enable function on pin 7 allows the detector to be strobed. The internal shield provides a guaranteed common mode transient immunity of 5 kV/µs for the VO2601 and VO2631 and 15 kV/µs for the VO2611 and VO4661. The use of a 0.1 µF bypass capacitor connected between pin 5 and 8 is recommended.

FEATURES





- High speed: 10 MBd typical
- +5 V CMOS compatibility
- Pure tin leads

RoHS

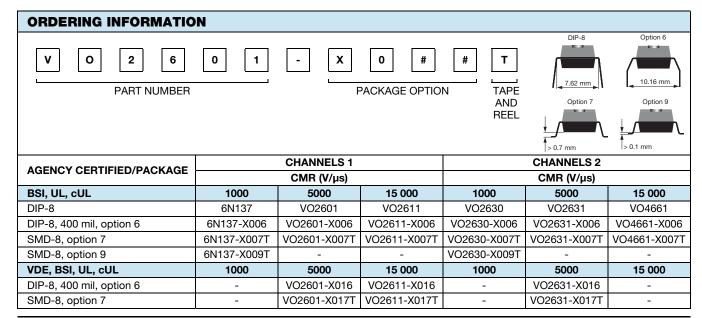
- Guaranteed AC and DC performance over temperature: -40 °C to +100 °C temperature range
- Meets IEC 60068-2-42 (SO₂) and IEC 60068-2-43 (H₂S) requirements
- Low input current capability of 5 mA
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Microprocessor system interface
- PLC, ATE input/output isolation
- Computer peripheral interface
- Digital fieldbus isolation: CC-link, DeviceNet, profibus, SDS
- High speed A/D and D/A conversion
- · AC plasma display panel level shifting
- Multiplexed data transmission
- · Digital control power supply
- Ground loop elimination, noise isolation

AGENCY APPROVALS

- UL1577
- cUL
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BS EN 60950-1
- CQC GB8898-2011, GB4943.1-2011





6N137, VO2601, VO2611, VO2630, VO2631, VO4661

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TRUTH TABLE (positive logic)						
LED	ENABLE	OUTPUT				
On	Н	L				
Off	Н	Н				
On	L	Н				
Off	L	Н				
On	NC	L				
Off	NC	Н				

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Average forward current (single channel)		I _F	20	mA			
Average forward current (per channel for dual channel)		l _F	15	mA			
Reverse input voltage		V _R	5	V			
Enable input voltage		V _E	V _{CC} + 0.5 V	V			
Enable input current		I _E	5	mA			
Surge current	t = 100 μs	I _{FSM}	200	mA			
Output power dissipation (single channel)		P _{diss}	35	mW			
Output power dissipation (per channel for dual channel)		P _{diss}	25	mW			
OUTPUT							
Supply voltage	1 min maximum	V _{CC}	7	V			
Output current		I _O	50	mA			
Output voltage		V _O	7	V			
Output power dissipation (single channel)		P _{diss}	85	mW			
Output power dissipation (per channel for dual channel)		P _{diss}	60	mW			
COUPLER							
Storage temperature		T _{stg}	-55 to +150	°C			
Operating temperature		T _{amb}	-40 to +100	°C			
Lead solder temperature	for 10 s		260	°C			
Solder reflow temperature			260	°C			

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

RECOMMENDED OPERATING CONDITIONS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT		
Operating temperature		T _{amb}	-40	100	°C		
Supply voltage		V _{CC}	4.5	5.5	V		
Input current low level		I _{FL}	0	250	μΑ		
Input current high level		I _{FH}	5	15	mA		
Logic high enable voltage		V _{EH}	2	V _{CC}	V		
Logic low enable voltage		V _{EL}	0	0.8	V		
Output pull up resistor		R_{L}	330	4K	Ω		
Fanout	$R_L = 1 \text{ k}\Omega$	N		5	-		



6N137, VO2601, VO2611, VO2630, VO2631, VO4661

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PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Input forward voltage	I _F = 10 mA	V_{F}	1.1	1.4	1.7	V
Reverse current	V _R = 5 V	I _R		0.01	10	μΑ
Input capacitance	f = 1 MHz, V _F = 0 V	Cı		55		pF
OUTPUT						
High level supply current	$V_E = 0.5 \text{ V}, I_F = 0 \text{ mA}$	I _{CCH}		4.1	7	mA
(single channel)	$V_E = V_{CC}$, $I_F = 0$ mA	Іссн		3.3	6	mA
High level supply current (dual channel)	I _F = 0 mA	I _F = 0 mA I _{CCH}		6.5	12	mA
Low level supply current (single channel)	$V_E = 0.5 \text{ V}, I_F = 10 \text{ mA}$	I _{CCL}		4	7	mA
	$V_E = V_{CC}, I_F = 10 \text{ mA}$	I _{CCL}		3.3	6	mA
Low level supply current (dual channel)	I _F = 10 mA	I _{CCL}		6.5	12	mA
High level output current	$V_E = 2 \text{ V}, V_{CC} = 5.5 \text{ V}, I_F = 250 \mu\text{A}$	I _{OH}		0.002	1	μΑ
Low level output voltage $V_E = 2 \text{ V}, I_F = 5 \text{ mA}, I_{OL} \text{ (sinking)} = 13 \text{ mA}$		V _{OL}		0.2	0.6	V
Input threshold current	$V_E = 2 \text{ V}, V_{CC} = 5.5 \text{ V},$ I_{OL} (sinking) = 13 mA	I _{TH}		2.4	5	mA
High level enable current	V _E = 2 V	I _{EH}		-0.6	-1.6	mA
Low level enable current	V _E = 0.5 V	I _{EL}		-0.8	-1.6	mA
High level enable voltage		V_{EH}	2			V
Low level enable voltage		V_{FL}			0.8	V

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Propagation delay time to high	D 050 0 0 15 = 5	t _{PLH}	20	48	75 ⁽¹⁾	ns	
output level	$R_L = 350 \Omega, C_L = 15 pF$	t _{PLH}			100	ns	
Propagation delay time to low	$R_1 = 350 \Omega, C_1 = 15 pF$	t _{PHL}	25	50	75 ⁽¹⁾	ns	
output level	n _L = 350 ½, C _L = 15 pr	t _{PHL}			100	ns	
Pulse width disortion	$R_L = 350 \Omega, C_L = 15 pF$	t _{PHL} - t _{PLH}		2.9	35	ns	
Propagation delay skew	$R_L = 350 \Omega, C_L = 15 pF$	t _{PSK}		8	40	ns	
Output rise time (10 % to 90 %)	$R_L = 350 \Omega, C_L = 15 pF$	t _r		23		ns	
Output fall time (90 % to 10 %)	$R_L = 350 \Omega, C_L = 15 pF$	t _f		7		ns	
Propagation delay time of enable from V _{EH} to V _{EL}	$R_L = 350 \ \Omega, \ C_L = 15 \ pF, \ V_{EL} = 0 \ V, \ V_{EH} = 3 \ V$	t _{ELH}		12		ns	
Propagation delay time of enable from V _{EL} to V _{EH}	$R_L = 350 \ \Omega, \ C_L = 15 \ pF, \ V_{EL} = 0 \ V, \ V_{EH} = 3 \ V$	t _{EHL}		11		ns	

Notes

Over recommended temperature (T_{amb} = - 40 °C to + 100 °C), V_{CC} = 5 V, I_F = 7.5 mA unless otherwise specified. All typicals at T_{amb} = 25 °C, V_{CC} = 5 V.

^{(1) 75} ns applies to the 6N137 only, a JEDEC® registered specification

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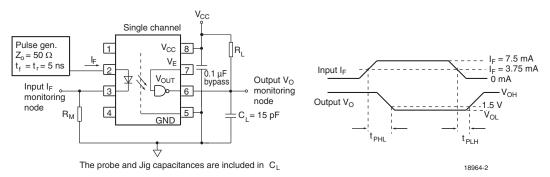


Fig. 1 - Single Channel Test Circuit for $t_{\text{PLH}},\,t_{\text{PHL}},\,t_{\text{r}}$ and t_{f}

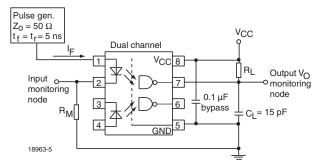


Fig. 2 - Dual Channel Test Circuit for $t_{\text{PLH}},\,t_{\text{PHL}},\,t_{\text{r}}$ and t_{f}

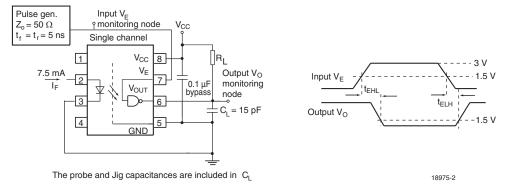


Fig. 3 - Single Channel Test Circuit for t_{EHL}, and t_{ELH}

COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	$ V_{CM} = 10 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}, V_{O(min.)} = 2 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ}C^{(1)}$	CM _H	1000			V/µs	
	$ V_{CM} = 50 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}, V_{O(min.)} = 2 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ}C$ (2)	CM _H	5000	10 000		V/µs	
	$\begin{aligned} V_{CM} &= 1 \text{ kV, } V_{CC} = 5 \text{ V, } I_F = 0 \text{ mA,} \\ V_{O(min.)} &= 2 \text{ V, } R_L = 350 \Omega, T_{amb} = 25 ^{\circ}\text{C} ^{(3)} \end{aligned}$	CM _H	15 000	25 000		V/µs	
	$\begin{aligned} & V_{CM} = 10 \text{ V, } V_{CC} = 5 \text{ V, } I_F = 7.5 \text{ mA,} \\ &V_{O(\text{max.})} = 0.8 \text{ V, } R_L = 350 \Omega, \ T_{amb} = 25 ^{\circ}\text{C} \end{aligned} $	CM _L	1000			V/µs	
	$\begin{aligned} V_{CM} &= 50 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}, \\ V_{O(\text{max.})} &= 0.8 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ}\text{C} \end{aligned}$	CM _L	5000	10 000		V/µs	
	$ \begin{aligned} & V_{CM} = 1 \text{ kV, } V_{CC} = 5 \text{ V, } I_F = 7.5 \text{ mA,} \\ &V_{O(\text{max.})} = 0.8 \text{ V, } R_L = 350 \ \Omega, \ T_{amb} = 25 \ ^{\circ}\text{C} \ ^{(3)} \end{aligned} $	CM _L	15 000	25 000		V/µs	

Notes

- $^{(1)}$ For 6N137 and VO2630
- (2) For VO2601 and VO2631
- (3) For VO2611 and VO4661

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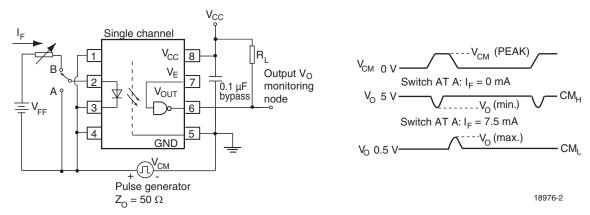


Fig. 4 - Single Channel Test Circuit for Common Mode Transient Immunity

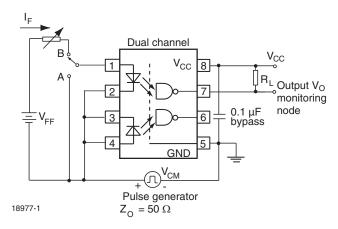


Fig. 5 - Dual Channel Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Climatic classification (according to IEC 68 part 1)			40/100/21				
Comparative tracking index		CTI	175				
Rated isolation voltage	t = 1 min	V _{ISO}	5300	V _{RMS}			
Maximum transient isolation voltage		V _{IOTM}	8000	V			
Maximum repetitive peak isolation voltage		V _{IORM}	890	V			
Indiation maintains	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
Output safety power		P _{SO}	500	mW			
Input safety current		I _{SI}	300	mA			
Input safety temperature		T _{SI}	175	°C			
Creepage distance	Standard DIP-4		≥ 8	mm			
Clearance distance	Standard DIP-4		≥ 8	mm			
Creepage distance	400 mil DIP-4		≥ 8	mm			
Clearance distance	400 mil DIP-4		≥ 8	mm			
Insulation thickness, reinforced rated	per BSI 60950	DTI	≥ 0.4	mm			

Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

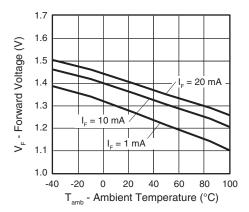


Fig. 6 - Forward Voltage vs. Ambient Temperature

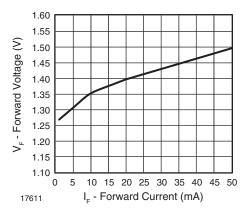


Fig. 7 - Forward Voltage vs. Forward Current

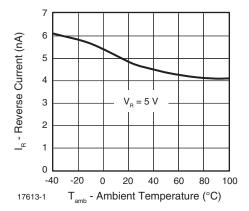


Fig. 8 - Reverse Current vs. Ambient Temperature

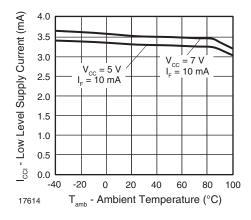


Fig. 9 - Low Level Supply Current vs. Ambient Temperature

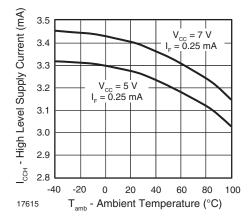


Fig. 10 - High Level Supply Current vs. Ambient Temperature

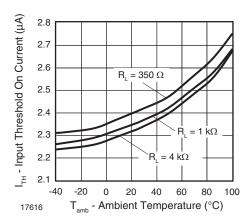


Fig. 11 - Input Threshold On Current vs. Ambient Temperature

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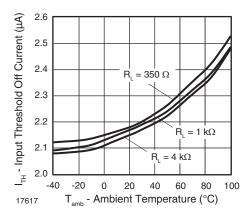


Fig. 12 - Input Threshold Off Current vs. Ambient Temperature

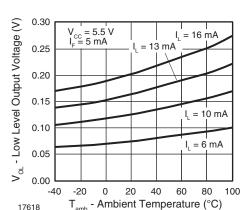


Fig. 13 - Low Level Output Voltage vs. Ambient Temperature

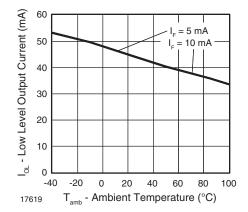


Fig. 14 - Low Level Output Current vs. Ambient Temperature

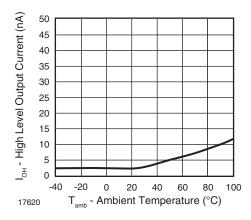


Fig. 15 - High Level Output Current vs. Ambient Temperature

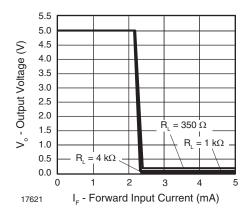


Fig. 16 - Output Voltage vs. Forward Input Current

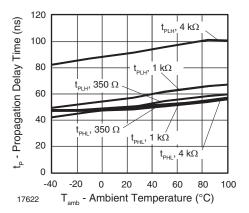


Fig. 17 - Propagation Delay vs. Ambient Temperature

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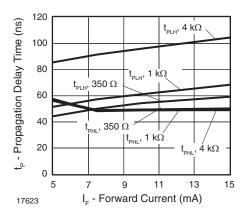


Fig. 18 - Propagation Delay vs. Forward Current

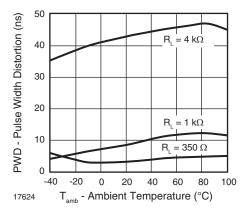


Fig. 19 - Pulse Width Distortion vs. Ambient Temperature

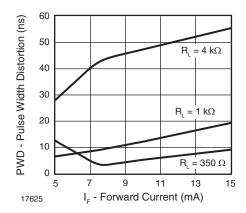


Fig. 20 - Pulse Width Distortion vs. Forward Current

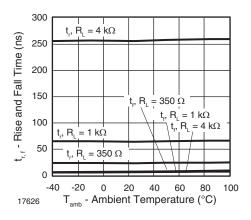


Fig. 21 - Rise and Fall Time vs. Ambient Temperature

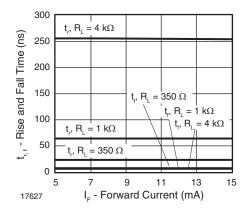


Fig. 22 - Rise and Fall Time vs. Forward Current

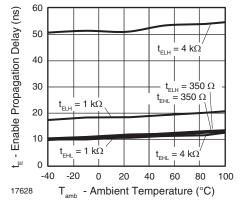


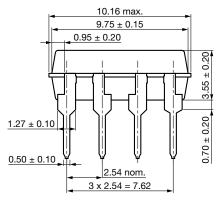
Fig. 23 - Enable Propagation Delay vs. Ambient Temperature

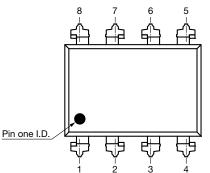


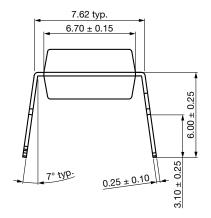
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PACKAGE DIMENSIONS in millimeters

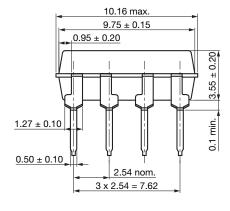
DIP-8, Standard

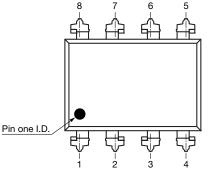


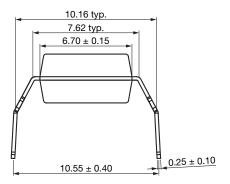




DIP-8, Option 6





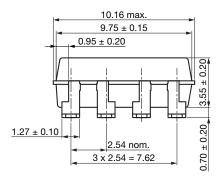


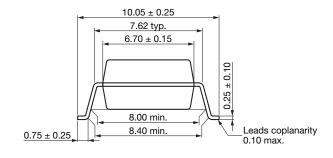


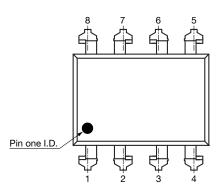


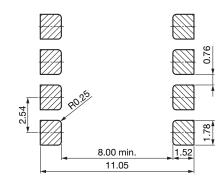
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SMD-8, Option 7

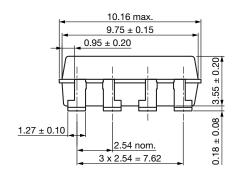


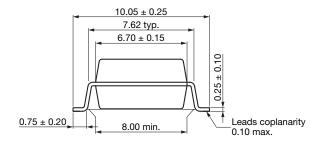


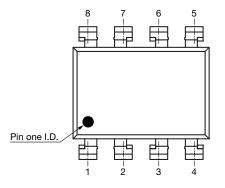


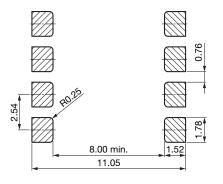


SMD-8, Option 9





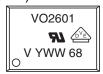




6N137, VO2601, VO2611, VO2630, VO2631, VO4661

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PACKAGE MARKING (example of VO2601-X017T)



Notes

- VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

SOLDER PROFILES

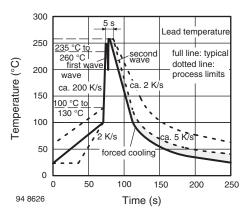


Fig. 24 - Wave Soldering Double Wave Profile According to J.STD-020 for DIP-8 Devices

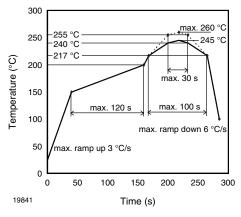


Fig. 25 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD-8 Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



Legal Disclaimer Notice

Vishay

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Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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